

Test Report

No.: ETR23804268M01

Date: 29-Aug-2023

Page: 1 of 13

POWERCHIP SEMICONDUCTOR MANUFACTURING CORPORATION
NO.12, LI-HSIN RD.1, HSINCHU SCIENCE PARK, HSINCHU, TAIWAN, 300 R.O.C

The following sample(s) was/were submitted and identified by the applicant as:

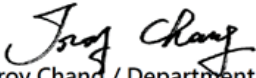
Sample Submitted By : POWERCHIP SEMICONDUCTOR MANUFACTURING CORPORATION
Sample Name : 12 INCH WAFER
Style/Item No. : PSMC FINISHED WAFER-AL PROCESS


=====
Sample Receiving Date : 21-Aug-2023
Testing Period : 21-Aug-2023 to 29-Aug-2023

Test Requested : (1) As specified by client, with reference to RoHS 2011/65/EU Annex II and amending Directive (EU) 2015/863 to determine Cadmium, Lead, Mercury, Cr(VI), PBBs, PBDEs, DBP, BBP, DEHP, DIBP contents in the submitted sample(s).
(2) Please refer to next pages for the other item(s).

Test Results : Please refer to following pages.

Conclusion : (1) Based on the performed tests on submitted sample(s), the test results of Cadmium, Lead, Mercury, Cr(VI), PBBs, PBDEs, DBP, BBP, DEHP, DIBP comply with the limits as set by RoHS Directive (EU) 2015/863 amending Annex II to Directive 2011/65/EU.


Troy Chang / Department Manager
Signed for and on behalf of
SGS TAIWAN LTD.
Chemical Laboratory - Taipei



PIN CODE: 413CD457

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POWERCHIP SEMICONDUCTOR MANUFACTURING CORPORATION
NO.12, LI-HSIN RD.1, HSINCHU SCIENCE PARK, HSINCHU, TAIWAN, 300 R.O.C

Test Part Description

No.1 : WAFER

Test Result(s)

Test Item(s)	Method	Unit	MDL	Result	Limit
				No.1	
Cadmium (Cd)	With reference to IEC 62321-5: 2013, analysis was performed by ICP-OES.	mg/kg	2	n.d.	100
Lead (Pb)		mg/kg	2	n.d.	1000
Mercury (Hg)	With reference to IEC 62321-4: 2013+ AMD1: 2017, analysis was performed by ICP-OES.	mg/kg	2	n.d.	1000
Hexavalent Chromium Cr(VI)	With reference to IEC 62321-7-2: 2017, analysis was performed by UV-VIS.	mg/kg	8	n.d.	1000
Monobromobiphenyl	With reference to IEC 62321-6: 2015, analysis was performed by GC/MS.	mg/kg	5	n.d.	-
Dibromobiphenyl		mg/kg	5	n.d.	-
Tribromobiphenyl		mg/kg	5	n.d.	-
Tetrabromobiphenyl		mg/kg	5	n.d.	-
Pentabromobiphenyl		mg/kg	5	n.d.	-
Hexabromobiphenyl		mg/kg	5	n.d.	-
Heptabromobiphenyl		mg/kg	5	n.d.	-
Octabromobiphenyl		mg/kg	5	n.d.	-
Nonabromobiphenyl		mg/kg	5	n.d.	-
Decabromobiphenyl		mg/kg	5	n.d.	-
Sum of PBBs		mg/kg	-	n.d.	1000
Monobromodiphenyl ether		mg/kg	5	n.d.	-
Dibromodiphenyl ether		mg/kg	5	n.d.	-
Tribromodiphenyl ether		mg/kg	5	n.d.	-
Tetrabromodiphenyl ether		mg/kg	5	n.d.	-
Pentabromodiphenyl ether		mg/kg	5	n.d.	-
Hexabromodiphenyl ether		mg/kg	5	n.d.	-
Heptabromodiphenyl ether		mg/kg	5	n.d.	-
Octabromodiphenyl ether		mg/kg	5	n.d.	-
Nonabromodiphenyl ether		mg/kg	5	n.d.	-
Decabromodiphenyl ether	mg/kg	5	n.d.	-	
Sum of PBDEs	mg/kg	-	n.d.	1000	

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POWERCHIP SEMICONDUCTOR MANUFACTURING CORPORATION
NO.12, LI-HSIN RD.1, HSINCHU SCIENCE PARK, HSINCHU, TAIWAN, 300 R.O.C

Test Item(s)	Method	Unit	MDL	Result	Limit
				No.1	
Butyl benzyl phthalate (BBP)	With reference to IEC 62321-8: 2017, analysis was performed by GC/MS.	mg/kg	50	n.d.	1000
Dibutyl phthalate (DBP)	With reference to IEC 62321-8: 2017, analysis was performed by GC/MS.	mg/kg	50	n.d.	1000
Di-(2-ethylhexyl) phthalate (DEHP)	With reference to IEC 62321-8: 2017, analysis was performed by GC/MS.	mg/kg	50	n.d.	1000
Diisobutyl phthalate (DIBP)	With reference to IEC 62321-8: 2017, analysis was performed by GC/MS.	mg/kg	50	n.d.	1000
Chlorine (Cl) (CAS No.: 22537-15-1)	With reference to BS EN 14582: 2016, analysis was performed by IC.	mg/kg	50	n.d.	-
Bromine (Br) (CAS No.: 10097-32-2)	With reference to BS EN 14582: 2016, analysis was performed by IC.	mg/kg	50	n.d.	-
Diisodecyl phthalate (DIDP) (CAS No.: 26761-40-0, 68515-49-1)	With reference to IEC 62321-8: 2017, analysis was performed by GC/MS.	mg/kg	50	n.d.	-
Diisononyl phthalate (DINP) (CAS No.: 28553-12-0, 68515-48-0)	With reference to IEC 62321-8: 2017, analysis was performed by GC/MS.	mg/kg	50	n.d.	-
Di-n-octyl phthalate (DNOP) (CAS No.: 117-84-0)	With reference to IEC 62321-8: 2017, analysis was performed by GC/MS.	mg/kg	50	n.d.	-
Di-n-pentyl phthalate (DNPP) (CAS No.: 131-18-0)	With reference to IEC 62321-8: 2017, analysis was performed by GC/MS.	mg/kg	50	n.d.	-
Di-n-hexyl phthalate (DNHP) (CAS No.: 84-75-3)	With reference to IEC 62321-8: 2017, analysis was performed by GC/MS.	mg/kg	50	n.d.	-
Bis(2-methoxyethyl) phthalate (DMEP) (CAS No.: 117-82-8)	With reference to IEC 62321-8: 2017, analysis was performed by GC/MS.	mg/kg	50	n.d.	-
Hexabromocyclododecane (HBCDD) and all major diastereoisomers identified (α - HBCDD, β - HBCDD, γ - HBCDD) (CAS No.: 25637-99-4, 3194-55-6 (134237-51-7, 134237-50-6, 134237-52-8))	With reference to IEC 62321: 2008, analysis was performed by GC/MS.	mg/kg	5	n.d.	-
PFOS and its salts (CAS No.: 1763-23-1 and its salts)	With reference to CEN/TS 15968: 2010, analysis was performed by LC/MS/MS.	mg/kg	0.01	n.d.	-
PFOA and its salts (CAS No.: 335-67-1 and its salts)	With reference to CEN/TS 15968: 2010, analysis was performed by LC/MS/MS.	mg/kg	0.01	n.d.	-

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NO.12, LI-HSIN RD.1, HSINCHU SCIENCE PARK, HSINCHU, TAIWAN, 300 R.O.C

Test Item(s)	Method	Unit	MDL	Result	Limit
				No.1	
Arsenic (As) (CAS No.: 7440-38-2)	With reference to US EPA 3052: 1996, analysis was performed by ICP-OES.	mg/kg	2	n.d.	-
Beryllium (Be) (CAS No.: 7440-41-7)	With reference to US EPA 3052: 1996, analysis was performed by ICP-OES.	mg/kg	2	n.d.	-
Antimony (Sb) (CAS No.: 7440-36-0)	With reference to US EPA 3052: 1996, analysis was performed by ICP-OES.	mg/kg	2	n.d.	-
Red Phosphorus	Analysis was performed by Pyrolyzer-GC/MS.	**	-	Negative	-

Note :

1. mg/kg = ppm ; 0.1wt% = 0.1% = 1000ppm
2. MDL = Method Detection Limit
3. n.d. = Not Detected (Less than MDL)
4. "-" = Not Regulated
5. **= Qualitative analysis (No Unit)
6. Negative = Undetectable ; Positive = Detectable
7. PFOS and its salts including :
CAS No.: 1763-23-1, 2795-39-3, 29457-72-5, 29081-56-9, 70225-14-8, 56773-42-3, 251099-16-8, 307-35-7, 91036-71-4, 4021-47-0 and others.
8. PFOA and its salts including :
CAS No.: 335-67-1, 335-95-5, 2395-00-8, 335-93-3, 335-66-0, 3825-26-1 and others.
9. Unless otherwise stated , the decision rule for conformity reporting is based on Binary Statement for Simple Acceptance Rule (w=0) stated in ILAC-G8:09/2019. According to this rule, the judgement of conformity is based on the comparing test results with limits.
10. This is the additional test report of ETR23804268.

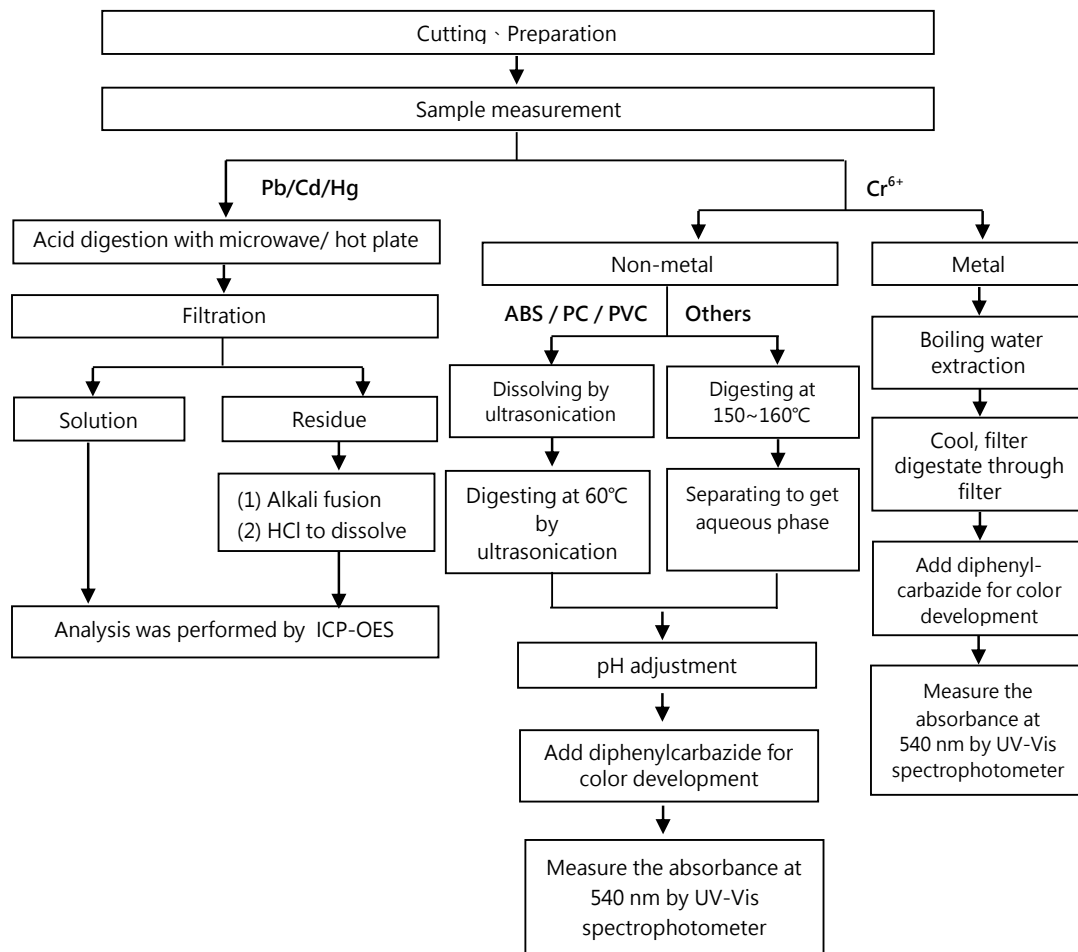
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POWERCHIP SEMICONDUCTOR MANUFACTURING CORPORATION
 NO.12, LI-HSIN RD.1, HSINCHU SCIENCE PARK, HSINCHU, TAIWAN, 300 R.O.C

Analytical flow chart of heavy metal

These samples were dissolved totally by pre-conditioning method according to below flow chart.

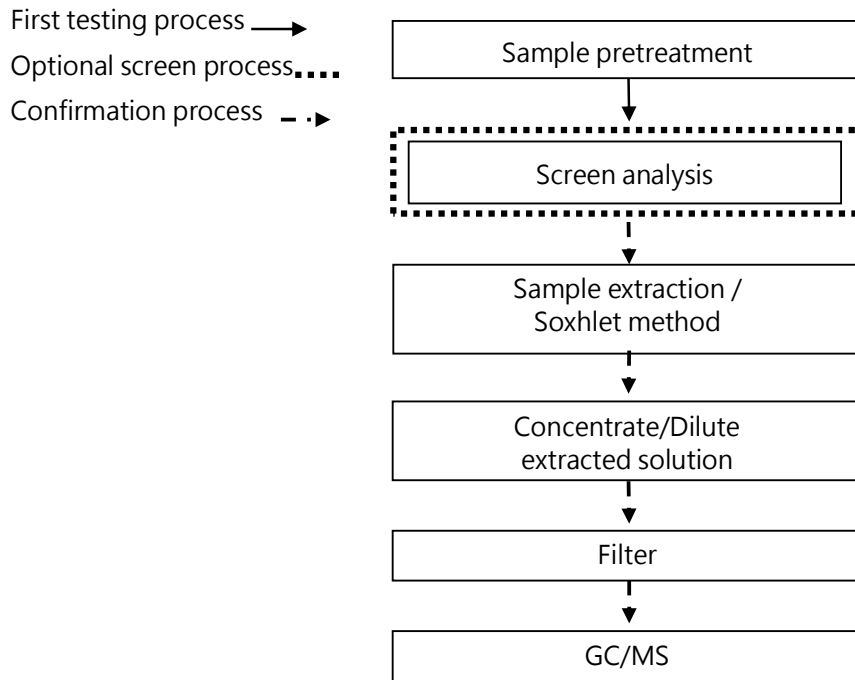
(Cr⁶⁺ test method excluded)



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Analytical flow chart – PBBs / PBDEs

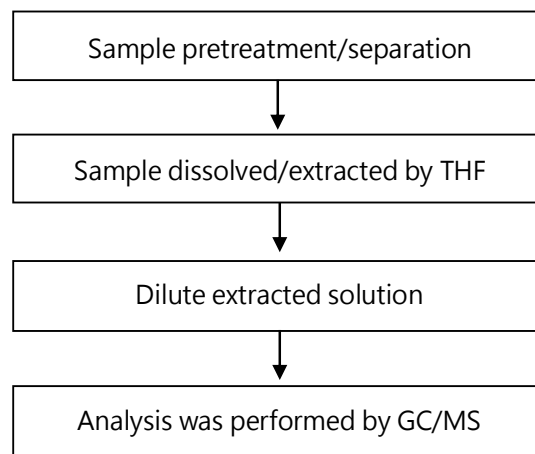


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Analytical flow chart - Phthalate

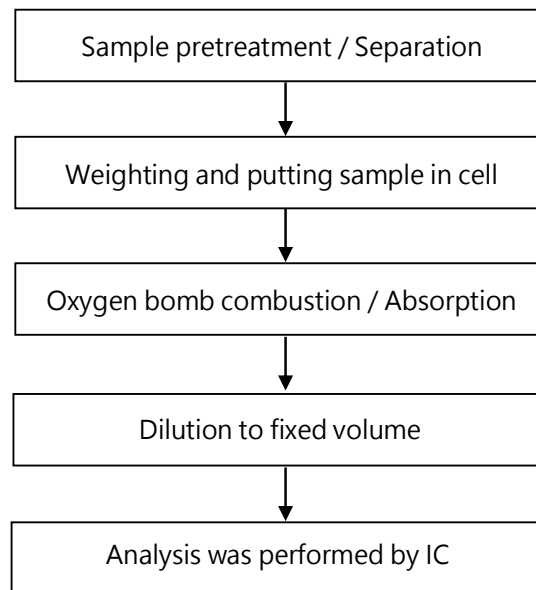
【Test method: IEC 62321-8】



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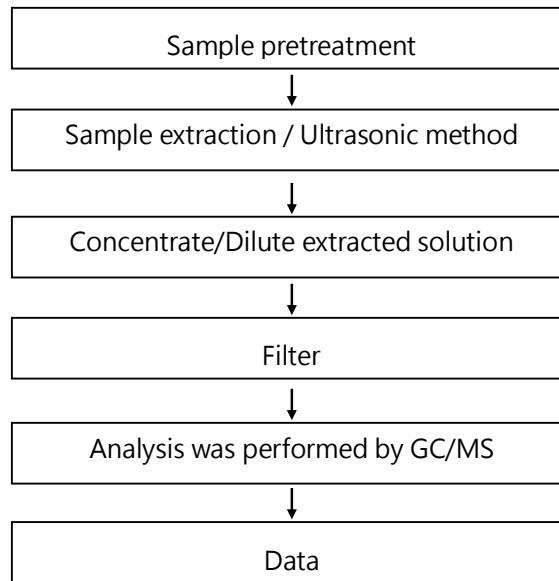
Analytical flow chart - Halogen



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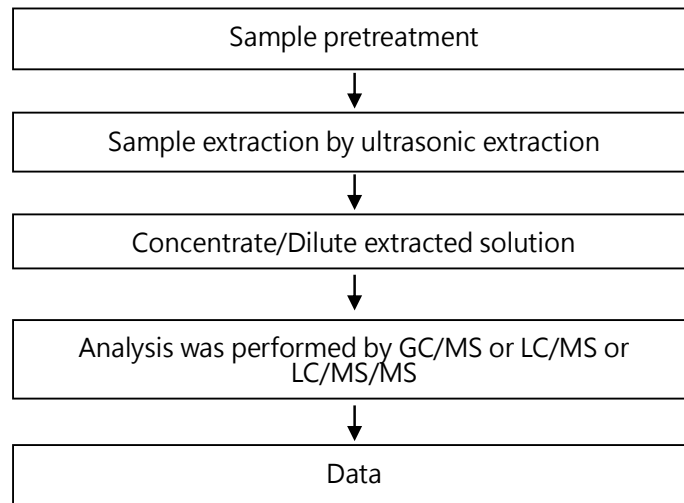
Analytical flow chart - HBCDD



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Analytical flow chart – PFAS (including PFOA/PFOS/its related compound, etc.)



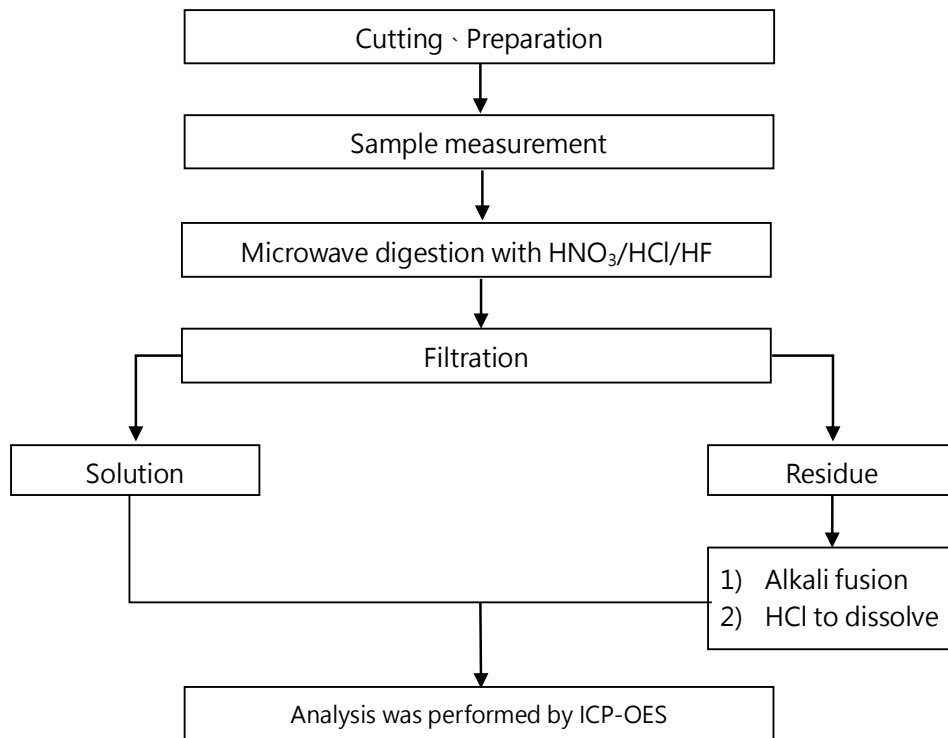
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Analytical flow chart of elements (Heavy metal included)

These samples were dissolved totally by pre-conditioning method according to below flow chart.

【Reference method : US EPA 3051A 、 US EPA 3052】

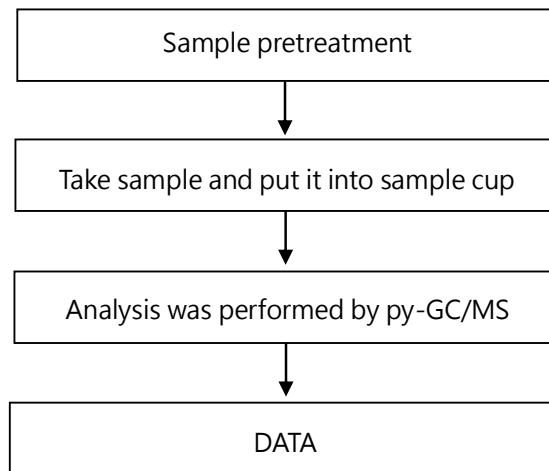


* US EPA 3051A method does not add HF.

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Analytical flow chart - Red phosphorus

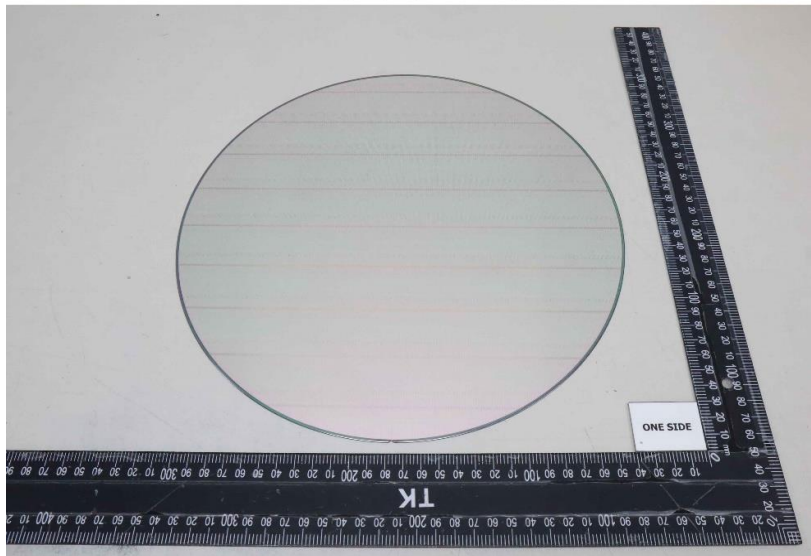


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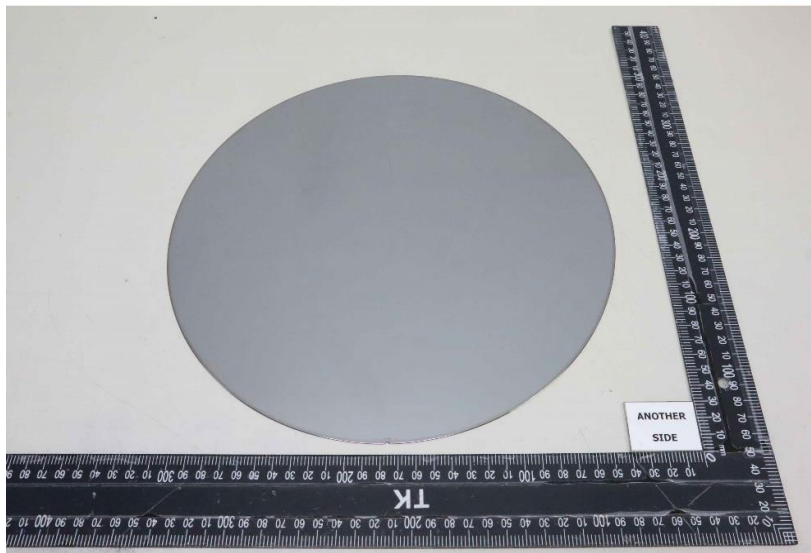
POWERCHIP SEMICONDUCTOR MANUFACTURING CORPORATION
NO.12, LI-HSIN RD.1, HSINCHU SCIENCE PARK, HSINCHU, TAIWAN, 300 R.O.C

* The tested sample / part is marked by an arrow if it's shown on the photo. *

ETR23804268



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** End of Report **

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